

# 1A, 50V - 1000V High Efficient Surface Mount Rectifier

#### **FEATURES**

- Glass passivated junction chip
- Ideal for automated placement
- Low profile package
- · Low power loss, high efficiency
- Fast switching for high efficiency
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

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- High frequency rectification
- Freewheeling application
- Switching mode converters and inverters in computer and telecommunication.

#### **MECHANICAL DATA**

- Case: SOD-123FL
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 0.019 g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I <sub>F</sub>	1	Α		
$V_{RRM}$	50 - 1000	<b>V</b>		
I <sub>FSM</sub>	30	Α		
T <sub>J MAX</sub>	150	°C		
Package SOD-123FL				





SOD-123FL

DADAMETED	CAMBO	HS1A	HS1B	HS1D	HS1F	HS1G	HS1J	HS1K	HS1M	
PARAMETER	SYMBOL	FL	FL	FL	FL	FL	FL	FL	FL	UNIT
Marking code on the device		HAF	HBF	HDF	HFF	HGF	HJF	HKF	HMF	
Repetitive peak reverse voltage	$V_{RRM}$	50	100	200	300	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	210	280	420	560	700	V
Forward current	I <sub>F</sub>				•	1				Α
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	30					А			
Junction temperature	$T_J$	- 55 to +150					°C			
Storage temperature	T <sub>STG</sub>	- 55 to +150				°C				



THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP.	UNIT		
Junction-to-lead thermal resistance per diode	$R_{\Theta JL}$	17	°C/W		
Junction-to-ambient thermal resistance per diode	$R_{\Theta JA}$	85	°C/W		
Junction-to-case thermal resistance per diode	R <sub>eJC</sub>	19	°C/W		

**Thermal Performance Note:** Units mounted on PCB (5mm x 5mm Cu pad test board)

PARAMETER		CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
	LICAAFI	I <sub>F</sub> = 0.5A, T <sub>J</sub> = 25°C		0.82	-	V
(1)	HS1AFL HS1BFL	I <sub>F</sub> = 1.0A, T <sub>J</sub> = 25°C	V <sub>F</sub>	0.89	0.95	V
Forward voltage per diode (1)	HS1DFL HS1FFL	I <sub>F</sub> = 0.5A, T <sub>J</sub> = 125°C		0.67	-	V
		I <sub>F</sub> = 1.0A, T <sub>J</sub> = 125°C		0.75	0.81	V
		I <sub>F</sub> = 0.5A, T <sub>J</sub> = 25°C		0.93	-	V
(4)		I <sub>F</sub> = 1.0A, T <sub>J</sub> = 25°C		1.01	1.30	V
Forward voltage per diode (1)	HS1GFL	I <sub>F</sub> = 0.5A, T <sub>J</sub> = 125°C	V <sub>F</sub>	0.74	-	V
		I <sub>F</sub> = 1.0A, T <sub>J</sub> = 125°C		0.85	1.10	V
		I <sub>F</sub> = 0.5A, T <sub>J</sub> = 25°C	V <sub>F</sub>	1.21	-	V
(4)	HS1JFL	I <sub>F</sub> = 1.0A, T <sub>J</sub> = 25°C		1.36	1.70	V
Forward voltage per diode (1)	HS1KFL HS1MFL	I <sub>F</sub> = 0.5A, T <sub>J</sub> = 125°C		0.94	-	V
		I <sub>F</sub> = 1.0A, T <sub>J</sub> = 125°C		1.10	1.38	V
5	T <sub>J</sub> = 25°C		-	5	μA	
Reverse current @ rated V <sub>R</sub> per o	diode (2)	T <sub>J</sub> = 125°C	- I <sub>R</sub>	-	150	μA
Junction capacitance	HS1AFL HS1BFL HS1DFL HS1FFL HS1GFL	1 MHz, V <sub>R</sub> =4.0V	CJ	11	-	pF
	HS1JFL HS1KFL HS1MFL			6	-	pF
Reverse recovery time	HS1AFL HS1BFL HS1DFL HS1FFL HS1GFL	I <sub>F</sub> =0.5A ,I <sub>R</sub> =1.0A I <sub>RR</sub> =0.25A	t <sub>rr</sub>	-	50	ns
	HS1JFL HS1KFL HS1MFL	- IKK-0.20/1	t <sub>rr</sub>	-	75	ns

#### Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms



RING INFORMATION		
ORDERING CODE	PACKAGE	PACKING
HS1AFL RVG	SOD-123FL	3,000 / 7" Plastic reel
HS1BFL RVG	SOD-123FL	3,000 / 7" Plastic reel
HS1DFL RVG	SOD-123FL	3,000 / 7" Plastic reel
HS1FFL RVG	SOD-123FL	3,000 / 7" Plastic reel
HS1GFL RVG	SOD-123FL	3,000 / 7" Plastic reel
HS1JFL RVG	SOD-123FL	3,000 / 7" Plastic reel
HS1KFL RVG	SOD-123FL	3,000 / 7" Plastic reel
HS1MFL RVG	SOD-123FL	3,000 / 7" Plastic reel



#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

**Fig.1 Forward Current Derating Curve** 

1.5 (V) LN AVO COLVERNIA 1 Heat sink 5mm x 5mm Cu pad test board 0 25 50 75 100 125 150 LEAD TEMPERATURE (C)

Fig.2 Typical Junction Capacitance

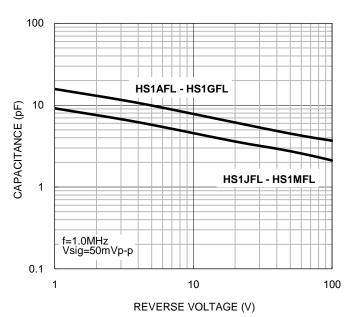
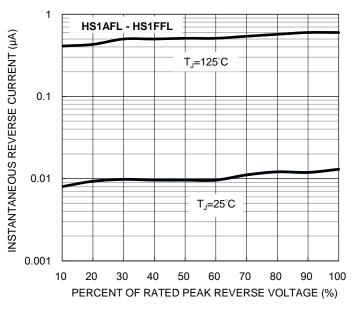
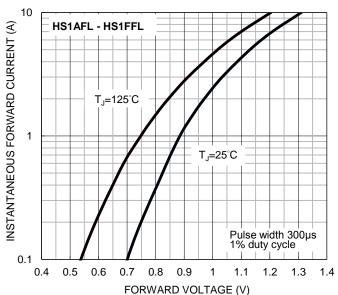


Fig.3 Typical Reverse Characteristics

Fig.4 Typical Forward Characteristics







#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

0.001

10

30

40

Fig.5 Typical Reverse Characteristics

10 INSTANTANEOUS REVERSE CURRENT (µA) HS1GFL T<sub>.I</sub>=125°C 0.1 0.01

Fig.6 Typical Forward Characteristics

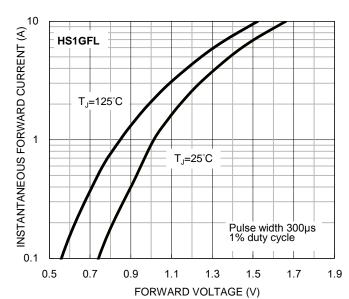


Fig.7 Typical Reverse Characteristics

PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

T<sub>J</sub>=25°C

60

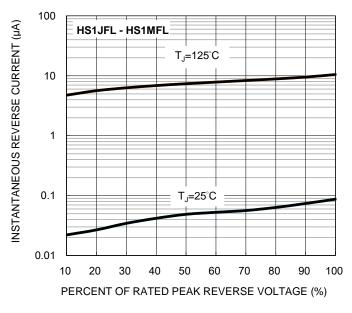
70

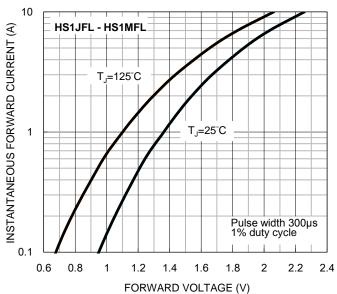
80

90

50



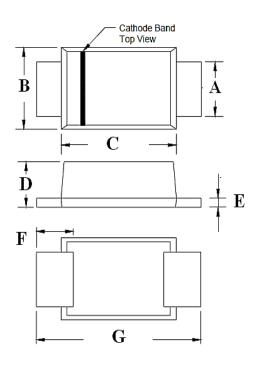






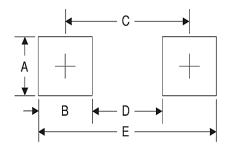
### **PACKAGE OUTLINE DIMENSIONS**

SOD-123FL



DIM.	Unit	(mm)	Unit (inch)		
DIIVI.	Min	Max	Min	Max	
Α	0.80	1.15	0.031	0.045	
В	1.70	2.10	0.067	0.083	
С	2.60	3.10	0.102	0.122	
D	0.88	1.35	0.035	0.053	
Е	0.10	0.30	0.004	0.012	
F	0.30	0.90	0.012	0.035	
G	3.45	3.95	0.136	0.156	

### **SUGGESTED PAD LAYOUT**



Symbol	Unit (mm)	Unit (inch)
А	1.4	0.055
В	1.2	0.047
С	3.1	0.122
D	1.9	0.075
E	4.3	0.169

## **MARKING DIAGRAM**



= Marking Code= Date Code P/N ΥW = Factory Code



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